## NSN 5961-01-272-9534

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-272-9534 **Inclosure Material:** Metal **Overall Length:** 2.900 inches **Overall Height:** 0.550 inches **Overall Width:** 1.900 inches **Function For Which Designed:** Transient suppressor **Mounting Facility Quantity: Component Name And Quantity:** 24 semiconductor device diode **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 39.0 breakdown voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 1.00 milliamperes forward current, average peak all semiconductor device diode **Power Rating Per Characteristic:** 24.0 watts small-signal input power, common-collector pascal all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 2 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: